



# Surface Mount RF Schottky Barrier Diodes

## Technical Data

### HSMS-281x Series

#### Features

- Surface Mount Packages
- Low Flicker Noise
- Low FIT (Failure in Time) Rate\*
- Six-sigma Quality Level
- Single, Dual and Quad Versions
- Tape and Reel Options Available

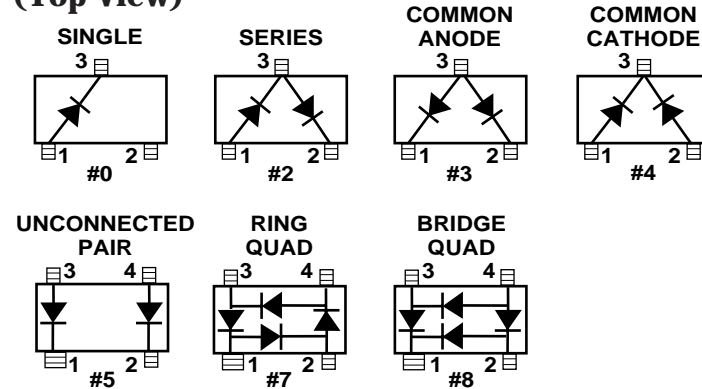
\* For more information see the Surface Mount Schottky Reliability Data Sheet.

#### Description/Applications

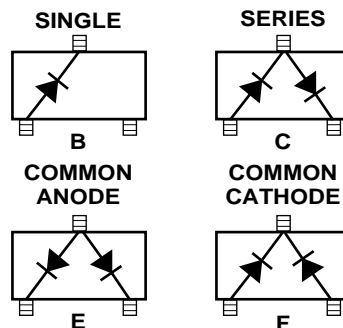
These Schottky diodes are specifically designed for both analog and digital applications. This series offers a wide range of specifications and package configurations to give the designer wide flexibility. The HSMS-281x series of diodes features very low flicker (1/f) noise.

Note that Agilent's manufacturing techniques assure that dice found in pairs and quads are taken from adjacent sites on the wafer, assuring the highest degree of match.

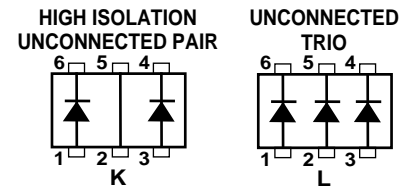
#### Package Lead Code Identification, SOT-23/SOT-143 (Top View)



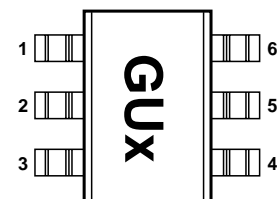
#### Package Lead Code Identification, SOT-323 (Top View)



#### Package Lead Code Identification, SOT-363 (Top View)



#### Pin Connections and Package Marking



#### Notes:

1. Package marking provides orientation and identification.
2. See "Electrical Specifications" for appropriate package marking.

### Absolute Maximum Ratings<sup>[1]</sup> $T_C = 25^\circ\text{C}$

Symbol	Parameter	Unit	SOT-23/SOT-143	SOT-323/SOT-363
$I_f$	Forward Current (1 $\mu\text{s}$ Pulse)	Amp	1	1
$P_{IV}$	Peak Inverse Voltage	V	Same as $V_{BR}$	Same as $V_{BR}$
$T_j$	Junction Temperature	$^\circ\text{C}$	150	150
$T_{stg}$	Storage Temperature	$^\circ\text{C}$	-65 to 150	-65 to 150
$\theta_{jc}$	Thermal Resistance <sup>[2]</sup>	$^\circ\text{C}/\text{W}$	500	150

#### Notes:

1. Operation in excess of any one of these conditions may result in permanent damage to the device.
2.  $T_C = +25^\circ\text{C}$ , where  $T_C$  is defined to be the temperature at the package pins where contact is made to the circuit board.

#### ESD WARNING:

Handling Precautions Should Be Taken To Avoid Static Discharge.

### Electrical Specifications $T_C = 25^\circ\text{C}$ , Single Diode<sup>[4]</sup>

Part Number HSMS <sup>[5]</sup>	Package Marking Code	Lead Code	Configuration	Minimum Breakdown Voltage $V_{BR}$ (V)	Maximum Forward Voltage $V_F$ (mV)	Maximum Forward Voltage $V_F$ (V) @ $I_F$ (mA)	Maximum Reverse Leakage $I_R$ (nA) @ $V_R$ (V)	Maximum Capacitance $C_T$ (pF)	Typical Dynamic Resistance $R_D$ ( $\Omega$ ) <sup>[6]</sup>						
2810	B0 <sup>[3]</sup>	0	Single	20	400	1.0 35	200 15	1.2	15						
2812	B2 <sup>[3]</sup>	2	Series												
2813	B3 <sup>[3]</sup>	3	Common Anode												
2814	B4 <sup>[3]</sup>	4	Common Cathode												
2815	B5 <sup>[3]</sup>	5	Unconnected Pair												
2817	B7 <sup>[3]</sup>	7	Ring Quad <sup>[5]</sup>												
2818	B8 <sup>[3]</sup>	8	Bridge Quad <sup>[5]</sup>												
281B	B0 <sup>[7]</sup>	B	Single												
281C	B2 <sup>[7]</sup>	C	Series												
281E	B3 <sup>[7]</sup>	E	Common Anode												
281F	B4 <sup>[7]</sup>	F	Common Cathode												
281K	BK <sup>[7]</sup>	K	High Isolation Unconnected Pair												
281L	BL <sup>[7]</sup>	L	Unconnected Trio												
Test Conditions										$I_R = 10 \mu\text{A}$	$I_F = 1 \text{mA}$			$V_F = 0 \text{V}$ $f = 1 \text{MHz}$	$I_F = 5 \text{mA}$

#### Notes:

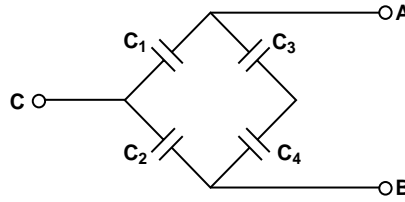
1.  $\Delta V_F$  for diodes in pairs and quads in 15 mV maximum at 1 mA.
2.  $\Delta C_{TO}$  for diodes in pairs and quads is 0.2 pF maximum.
3. Package marking code is in white.
4. Effective Carrier Lifetime ( $\tau$ ) for all these diodes is 100 ps maximum measured with Krakauer method at 5 mA.
5. See section titled "Quad Capacitance."
6.  $R_D = R_S + 5.2 \Omega$  at  $25^\circ\text{C}$  and  $I_F = 5 \text{mA}$ .
7. Package marking code is laser marked.

## Quad Capacitance

Capacitance of Schottky diode quads is measured using an HP4271 LCR meter. This instrument effectively isolates individual diode branches from the others, allowing accurate capacitance measurement of each branch or each diode. The conditions are: 20 mV R.M.S. voltage at 1 MHz. Agilent defines this measurement as "CM", and it is equivalent to the capacitance of the diode by itself. The equivalent diagonal and adjacent capacitances can then be calculated by the formulas given below.

In a quad, the diagonal capacitance is the capacitance between points A and B as shown in the figure below. The diagonal capacitance is calculated using the following formula

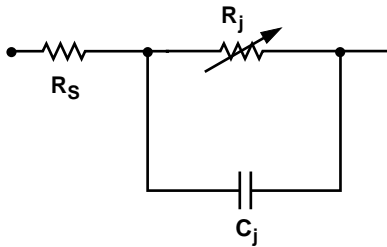
$$C_{\text{DIAGONAL}} = \frac{C_1 \times C_2}{C_1 + C_2} + \frac{C_3 \times C_4}{C_3 + C_4}$$



The equivalent adjacent capacitance is the capacitance between points A and C in the figure below. This capacitance is calculated using the following formula

$$C_{\text{ADJACENT}} = C_1 + \frac{1}{\frac{1}{C_2} + \frac{1}{C_3} + \frac{1}{C_4}}$$

## Linear Equivalent Circuit, Diode Chip



$R_s$  = series resistance (see Table of SPICE parameters)

$C_j$  = junction capacitance (see Table of SPICE parameters)

$$R_j = \frac{8.33 \times 10^{-5} \text{ nT}}{I_b + I_s}$$

where

$I_b$  = externally applied bias current in amps

$I_s$  = saturation current (see table of SPICE parameters)

$T$  = temperature, °K

$n$  = ideality factor (see table of SPICE parameters)

Note:

To effectively model the packaged HSMS-281x product, please refer to Application Note AN1124.

## SPICE Parameters

Parameter	Units	HSMS-281x
$B_V$	V	25
$C_{J0}$	pF	1.1
$E_G$	eV	0.69
$I_{BV}$	A	E-5
$I_S$	A	4.8E-9
$N$		1.08
$R_S$	$\Omega$	10
$P_B$	V	0.65
$P_T$		2
$M$		0.5

## Typical Performance, $T_C = 25^\circ\text{C}$ (unless otherwise noted), Single Diode

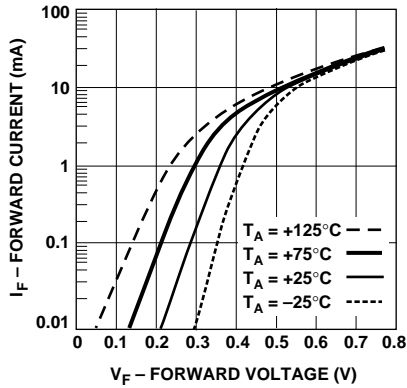


Figure 1. Forward Current vs. Forward Voltage at Temperatures.

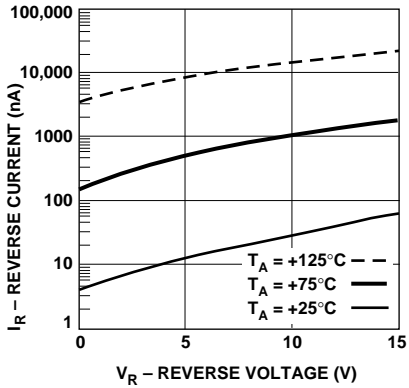


Figure 2. Reverse Current vs. Reverse Voltage at Temperatures.

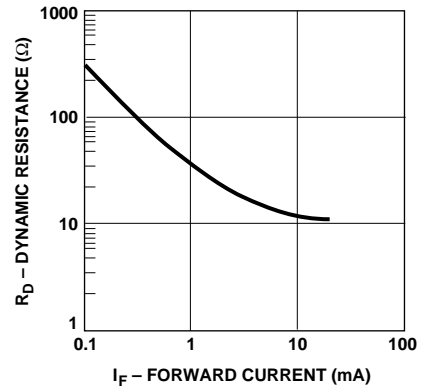


Figure 3. Dynamic Resistance vs. Forward Current.

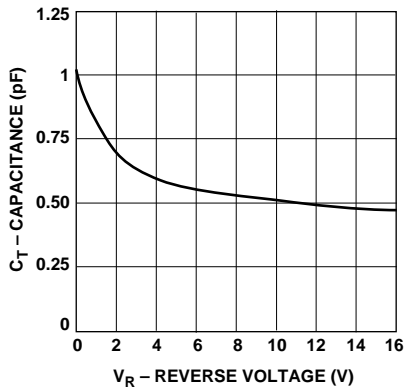


Figure 4. Total Capacitance vs. Reverse Voltage.

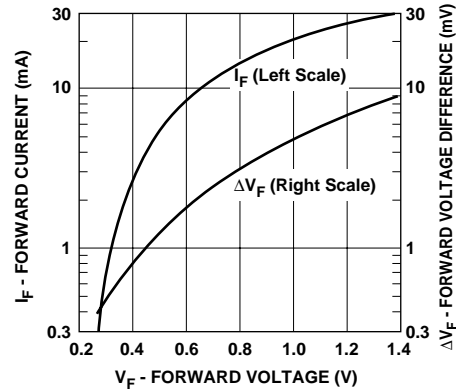


Figure 5. Typical  $V_f$  Match, Pairs and Quads.

## Applications Information

### Introduction — Product Selection

Agilent's family of Schottky products provides unique solutions to many design problems.

The first step in choosing the right product is to select the diode type. All of the products in the HSMS-282x family use the same diode chip, and the same is true of the HSMS-281x and HSMS-280x families. Each family has a different set of characteristics which can be compared most easily by consulting the SPICE parameters in Table 1.

A review of these data shows that the HSMS-280x family has the highest breakdown voltage, but at the expense of a high value of series resistance ( $R_S$ ). In applications which do not require high voltage the HSMS-282x family, with a lower value of series

resistance, will offer higher current carrying capacity and better performance. The HSMS-281x family is a hybrid Schottky (as is the HSMS-280x), offering lower 1/f or flicker noise than the HSMS-282x family.

In general, the HSMS-282x family should be the designer's first choice, with the -280x family reserved for high voltage applications and the HSMS-281x family for low flicker noise applications.

### Assembly Instructions

#### SOT-323 PCB Footprint

A recommended PCB pad layout for the miniature SOT-323 (SC-70) package is shown in Figure 6 (dimensions are in inches). This layout provides ample allowance for package placement by automated assembly equipment without adding parasitics that could impair the performance.

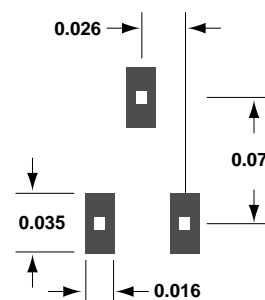


Figure 6. PCB Pad Layout (dimensions in inches).

#### Assembly Instructions SOT-363 PCB Footprint

A recommended PCB pad layout for the miniature SOT-363 (SC-70, 6 lead) package is shown in Figure 7 (dimensions are in inches). This layout provides ample allowance for package placement by automated assembly equipment without adding parasitics that could impair the performance.

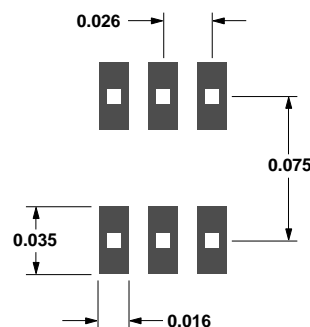


Figure 7. PCB Pad Layout (dimensions in inches).

Table 1. Typical SPICE Parameters.

Parameter	Units	HSMS-280x	HSMS-281x	HSMS-282x
$B_V$	V	75	25	15
$C_{J0}$	pF	1.6	1.1	0.7
$E_G$	eV	0.69	0.69	0.69
$I_{BV}$	A	1 E-5	1 E-5	1 E-4
$I_S$	A	3 E-8	4.8 E-9	2.2 E-8
N		1.08	1.08	1.08
$R_S$	$\Omega$	30	10	6.0
$P_B (V_J)$	V	0.65	0.65	0.65
$P_T (X_{TI})$		2	2	2
M		0.5	0.5	0.5

### SMT Assembly

Reliable assembly of surface mount components is a complex process that involves many material, process, and equipment factors, including: method of heating (e.g., IR or vapor phase reflow, wave soldering, etc.) circuit board material, conductor thickness and pattern, type of solder alloy, and the thermal conductivity and thermal mass of components. Components with a low mass, such as the SOT package, will reach solder reflow temperatures faster than those with a greater mass.

Agilent's SOT diodes have been qualified to the time-temperature profile shown in Figure 8. This profile is representative of an IR reflow type of surface mount assembly process.

After ramping up from room temperature, the circuit board with components attached to it (held in place with solder paste) passes through one or more preheat zones. The preheat zones increase the temperature of the board and components to prevent thermal shock and begin evaporating solvents from the solder paste. The reflow zone briefly elevates the temperature sufficiently to produce a reflow of the solder.

The rates of change of temperature for the ramp-up and cool-down zones are chosen to be low enough to not cause deformation of the board or damage to components due to thermal shock. The maximum temperature in the reflow zone ( $T_{MAX}$ ) should not exceed 235°C.

These parameters are typical for a surface mount assembly process for Agilent diodes. As a general guideline, the circuit board and components should be exposed only to the minimum temperatures and times necessary to achieve a uniform reflow of solder.

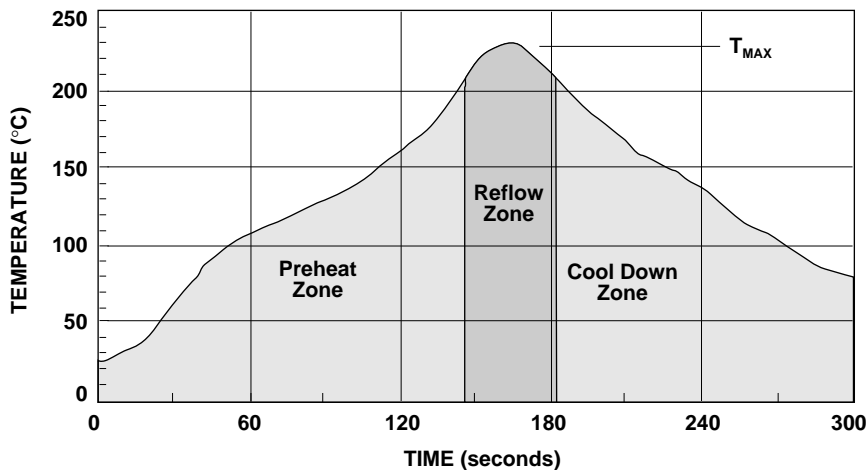


Figure 8. Surface Mount Assembly Profile.

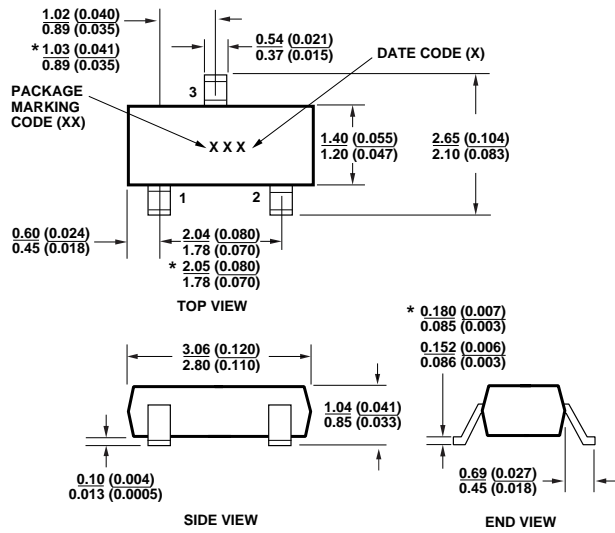
### Part Number Ordering Information

Part Number	No. of Devices	Container
HSMS-281x-TR2 *	10000	13" Reel
HSMS-281x-TR1 *	3000	7" Reel
HSMS-281x-BLK *	100	antistatic bag

x = 0, 2, 3, 4, 5, 7, 8, B, C, E, F, K, L

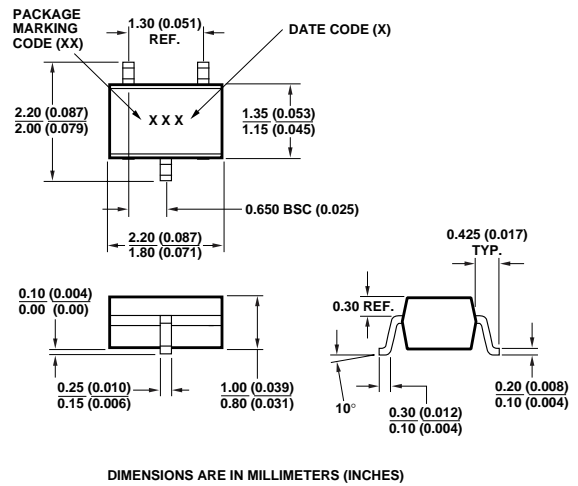
### Package Dimensions

#### Outline 23 (SOT-23)



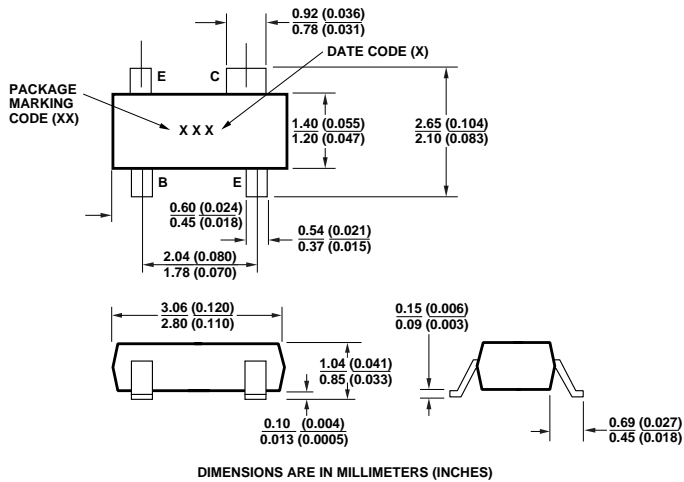
\* THESE DIMENSIONS FOR HSMS-280X AND -281X FAMILIES ONLY.  
DIMENSIONS ARE IN MILLIMETERS (INCHES)

#### Outline SOT-323 (SC-70 3 Lead)



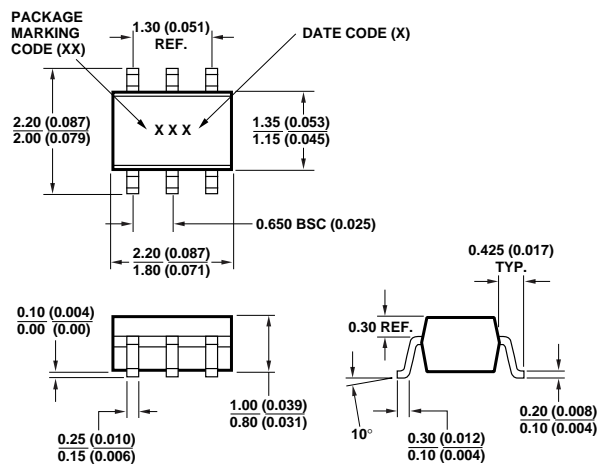
DIMENSIONS ARE IN MILLIMETERS (INCHES)

#### Outline 143 (SOT-143)



DIMENSIONS ARE IN MILLIMETERS (INCHES)

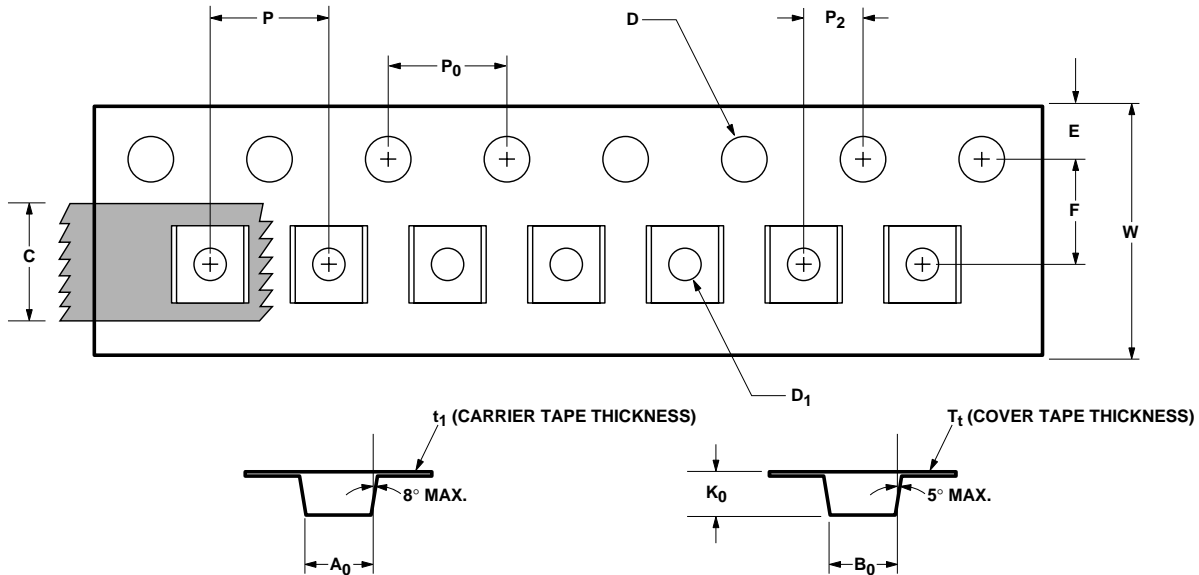
#### Outline SOT-363 (SC-70 6 Lead)



DIMENSIONS ARE IN MILLIMETERS (INCHES)



**Tape Dimensions and Product Orientation**  
**For Outline SOT-323 (SC-70 3 Lead)**



DESCRIPTION		SYMBOL	SIZE (mm)	SIZE (INCHES)
CAVITY	LENGTH	A <sub>0</sub>	2.24 ± 0.10	0.088 ± 0.004
	WIDTH	B <sub>0</sub>	2.34 ± 0.10	0.092 ± 0.004
	DEPTH	K <sub>0</sub>	1.22 ± 0.10	0.048 ± 0.004
	PITCH	P	4.00 ± 0.10	0.157 ± 0.004
	BOTTOM HOLE DIAMETER	D <sub>1</sub>	1.00 + 0.25	0.039 + 0.010
PERFORATION	DIAMETER	D	1.55 ± 0.05	0.061 ± 0.002
	PITCH	P <sub>0</sub>	4.00 ± 0.10	0.157 ± 0.004
	POSITION	E	1.75 ± 0.10	0.069 ± 0.004
CARRIER TAPE	WIDTH	W	8.00 ± 0.30	0.315 ± 0.012
	THICKNESS	t <sub>1</sub>	0.255 ± 0.013	0.010 ± 0.0005
COVER TAPE	WIDTH	C	5.4 ± 0.10	0.205 ± 0.004
	TAPE THICKNESS	T <sub>t</sub>	0.062 ± 0.001	0.0025 ± 0.00004
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION)	F	3.50 ± 0.05	0.138 ± 0.002
	CAVITY TO PERFORATION (LENGTH DIRECTION)	P <sub>2</sub>	2.00 ± 0.05	0.079 ± 0.002